

Low $V_{CE(sat)}$ transistor (strobe flash)

2SD2098 / 2SD2118

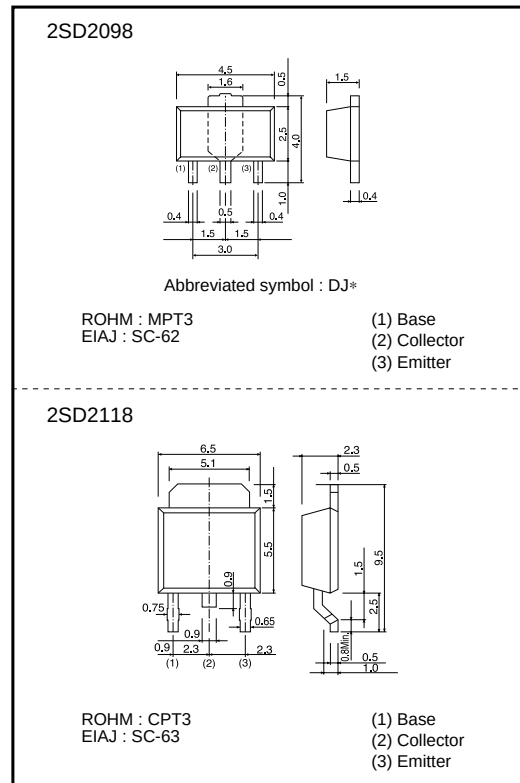
●Features

- 1) Low $V_{CE(sat)}$.
 $V_{CE(sat)} = 0.25V$ (Typ.)
 $(I_C/I_B = 4A / 0.1A)$
- 2) Excellent DC current gain characteristics.
- 3) Complements the 2SB1386 / 2SB1412.

●Structure

Epitaxial planar type
 NPN silicon transistor

●Dimensions (Unit : mm)



* Denotes h_{FE}

●Absolute maximum ratings ($T_a=25^\circ C$)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V_{CEO}	20	V
Emitter-base voltage		V_{EBO}	6	V
Collector current		I_C	5	A(DC)
		I_{CP}	10	A(Pulse) *1
Collector power dissipation	2SD2098	P_C	0.5	W *2
			2	
			1	
	2SD2118		10	W($T_c=25^\circ C$)
Junction temperature		T_j	150	$^\circ C$
Storage temperature		T_{stg}	-55 to +150	$^\circ C$

*1 Single pulse $P_w=10ms$

*2 When mounted on a 40×40×0.7 mm ceramic board.

Transistors

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV _{CB0}	50	–	–	V	I _C =50μA
Collector-emitter breakdown voltage	BV _{CEO}	20	–	–	V	I _C =1mA
Emitter-base breakdown voltage	BV _{EB0}	6	–	–	V	I _E =50μA
Collector cutoff current	I _{CB0}	–	–	0.5	μA	V _{CB} =40V
Emitter cutoff current	I _{EBO}	–	–	0.5	μA	V _{EB} =5V
Collector-emitter saturation voltage	V _{CE(sat)}	–	0.3	1.0	V	I _C /I _B =4A/0.1A *
DC current transfer ratio	h _{FE}	120	–	390	–	V _{CE} =2V, I _C =0.5A *
Transition frequency	f _T	–	150	–	MHz	V _{CE} =6V, I _E =–50mA, f=100MHz
Output capacitance	C _{ob}	–	35	–	pF	V _{CE} =20V, I _E =0A, f=1MHz

* Measured using pulse current.

●Packaging specifications and h_{FE}

Type	h _{FE}	Package	Taping	
		Code	T100	TL
		Basic ordering unit (pieces)	1000	2500
2SD2098	QR		○	–
2SD2118	QR		–	○

h_{FE} values are classified as follows :

Item	Q	R
h _{FE}	120 to 270	180 to 390

Transistors

●Electrical characteristic curves

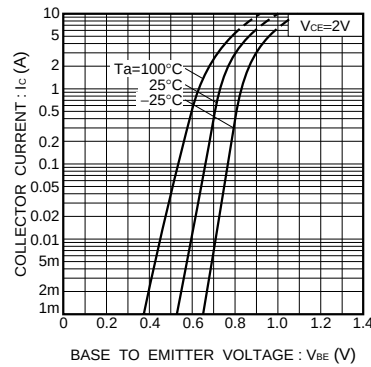


Fig.1 Grounded emitter propagation characteristics

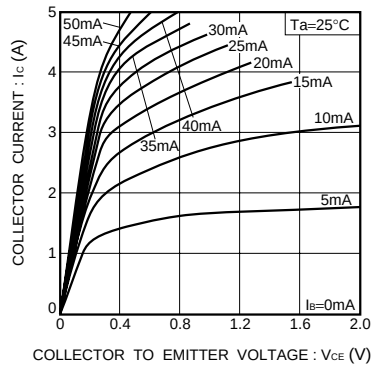


Fig.2 Grounded emitter output characteristics

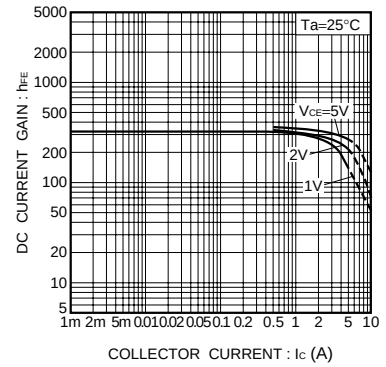


Fig.3 DC current gain vs. collector current (I)

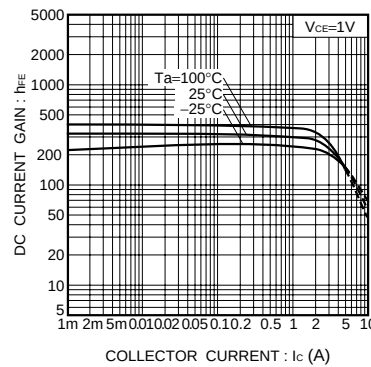


Fig.4 DC current gain vs. collector current (II)

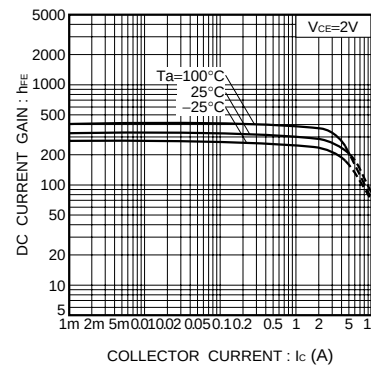


Fig.5 DC current gain vs. collector current (III)

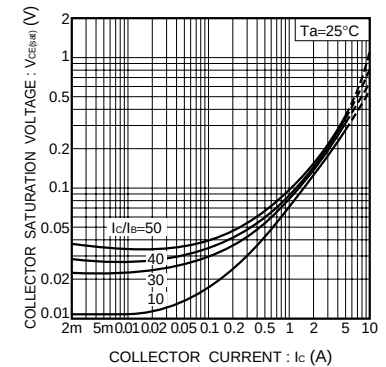


Fig.6 Collector-emitter saturation voltage vs. collector current (I)

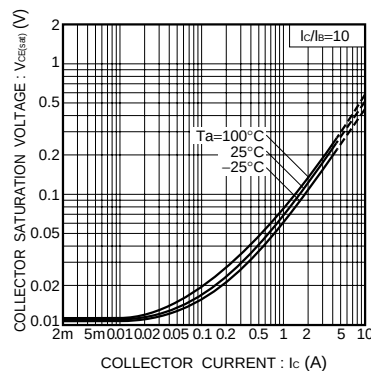


Fig.7 Collector-emitter saturation voltage vs. collector current (II)

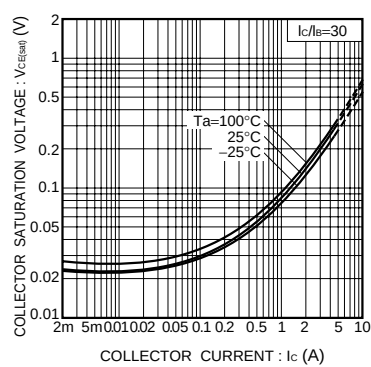


Fig.8 Collector-emitter saturation voltage vs. collector current (III)

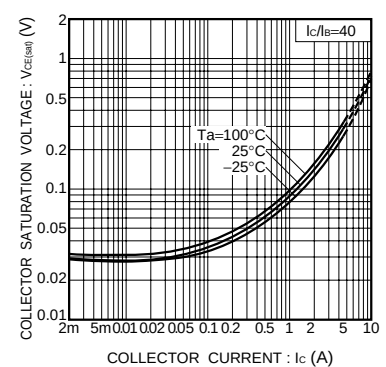


Fig.9 Collector-emitter saturation voltage vs. collector current (IV)

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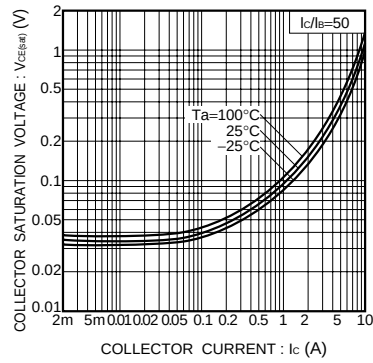


Fig.10 Collector-emitter saturation voltage vs. collector current (V)

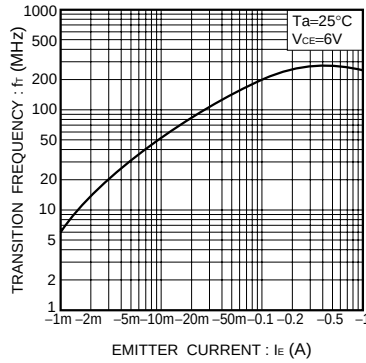


Fig.11 Gain bandwidth product vs. emitter current

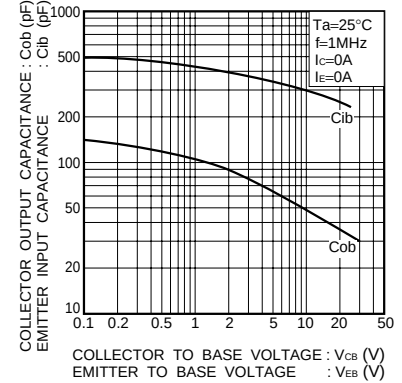


Fig.12 Collector output capacitance vs. collector-base voltage
Emitter input capacitance vs. emitter-base voltage

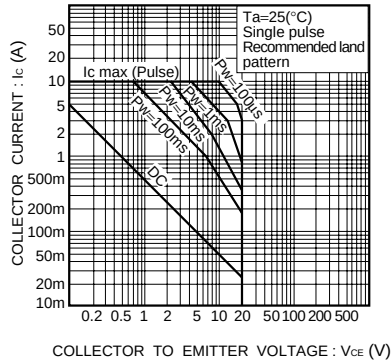


Fig.13 Safe operating area (2SD2098)

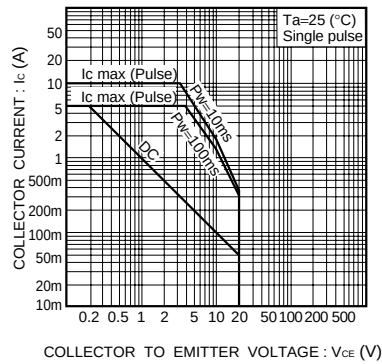


Fig.14 Safe operating area (2SD2118)

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